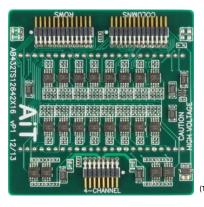
# **Summary**

### **Features**

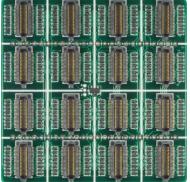
- Supports up to 16 Hamamatsu S12642-0404PB 4x4
   TSV MPPC arrays for up to 16x16 3mm MPPCs
- 4-channel readout or 32-channel readout
  - Four encoded position signals for event centroid calculations: X+, X-, Y+, Y-
  - 16 row signals and 16 column signals
- Patent-pending diode-coupled readout, superior to traditional resistive readout
  - Improved spatial uniformity
  - Faster rise time
  - Reduced image noise
- < 10ns rise time</li>
- DC-coupled signal path
- Low power consumption
- Precision temperature sensor

### Mechanical

- Installs within the perimeter of the SiPM array for 4sided tileable installation
- 0.050" pitch signal connectors use low-profile micro
   IDC cable assemblies for versatile placement

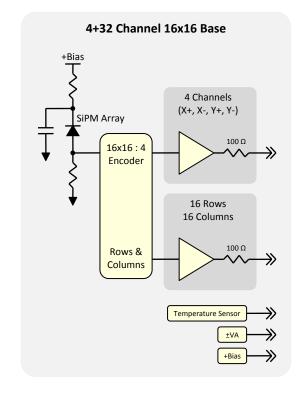






SiPM arrays not included

(Bottom View



### (Preliminary) Rev. 08/14

# **4-Channel Specifications**

**Position Signal Output** 

Channels 4

Encoding Charge division multiplexed to 4

output channels: X+, X-, Y+, Y-

Encoder gain  $375\Omega$  transimpedance gain

(high-Z load)

Rise time < 10 ns

Output voltage  $0 \rightarrow \pm 1V$  (100 $\Omega$  load)

 $\begin{array}{ll} \text{Output impedance} & 100\Omega \\ \text{Output current} & 50\text{mA max}. \end{array}$ 

**Temperature Sensor** 

Output voltage 500mV + 10mV per °C

 $\begin{array}{ll} \text{Output current} & 10\text{mA} \\ \text{Output impedance} & 100\Omega \\ \text{Accuracy} & \pm 0.5^{\circ}\text{C} \end{array}$ 

Bias Voltage +67.4V typ.

(refer to manufacturer's data)

Over-voltage clamp 82V Zener diode

Amplifier Voltage (±VA) ±2.8V typ.; ±5V max.

Current ±65mA typ.

(Iq, no signal, no load)

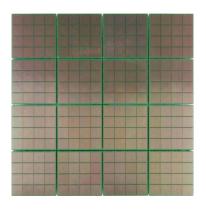
**Signal Connector** Right angle 16-pin 2-row header

0.050" pin pitch

Mating assembly Samtec FFSD-08-D-XX.XX-01-N

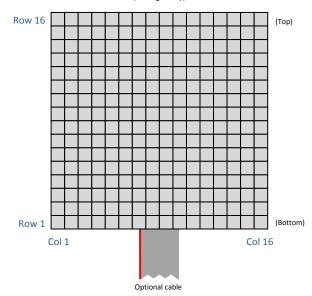
(XX.XX = length in inches)

### S12642-0404PB 4x4 Arrangement

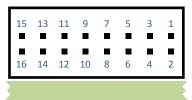


# **Array Channel Map**

(Facing Array)



# **Signal Connector**



**PCB Side View** 

Pin	Function	Pin	Function
1	Temperature	2	GND
3	Χ-	4	GND
5	X+	6	GND
7	-VA	8	GND
9	+VA	10	GND
11	Υ-	12	GND
13	Y+	14	GND
15	+Bias	16	GND

# **32-Channel Specifications**

### **Position Signal Output**

Channels 32

Encoding 16 rows & 16 columns Encoder gain 750Ω transimpedance gain

(high-Z load)

Rise time < 10 ns

Output voltage  $0 \rightarrow -1V$  (100 $\Omega$  load)

 $\begin{array}{ll} \text{Output impedance} & 100\Omega \\ \text{Output current} & 50\text{mA max}. \end{array}$ 

### **Temperature Sensor**

Output voltage 500mV + 10mV per °C

 $\begin{array}{ll} \text{Output current} & 10\text{mA} \\ \text{Output impedance} & 100\Omega \\ \text{Accuracy} & \pm 0.5^{\circ}\text{C} \end{array}$ 

Bias Voltage +67.4V typ.

(refer to manufacturer's data)

Over-voltage clamp 82V Zener diode

**NOTE** Bias voltage is on the ROWS

connector only. Bias voltage is disconnected from the COLUMNS

connector.

Amplifier Voltage (±VA) ±2.8V typ.; ±5V max.

Current ±65mA typ.

(Iq, no signal, no load)

Signal Connectors (2) Right angle 26-pin 2-row header

0.050" pin pitch

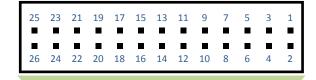
Mating assembly Samtec FFSD-13-D-XX.XX-01-N

(XX.XX = length in inches)

### **CAUTION**

Connect either the 4-channel connector or the ROWS & COLUMNS connectors, NOT BOTH. Applying bias voltage and power through the 4-channel connector and the ROWS connector at the same time may cause damage.

# Signal Connectors (2)



**PCB Side View** 

### **ROWS Connector**

Pin	Function	Pin	Function
1	Row 1	2	Temperature
3	Row 2	4	GND
5	Row 4	6	Row 3
7	Row 5	8	GND
9	Row 6	10	Row 7
11	Row 8	12	-VA
13	Row 9	14	GND
15	Row 10	16	+VA
17	Row 12	18	Row 11
19	Row 13	20	GND
21	Row 14	22	Row 15
23	Row 16	24	GND
25	+Bias	26	GND

### **COLUMNS Connector**

Pin	Function	Pin	Function
1	Column 1	2	Temperature
3	Column 2	4	GND
5	Column 4	6	Column 3
7	Column 5	8	GND
9	Column 6	10	Column 7
11	Column 8	12	no connect
13	Column 9	14	GND
15	Column 10	16	no connect
17	Column 12	18	Column 11
19	Column 13	20	GND
21	Column 14	22	Column 15
23	Column 16	24	GND
25	no connect	26	GND

# **4-Channel Position Encoder**

# **Row & Column Encoder Weighs**

Row# or Col# (for X- or Y-)	Row# or Col# (for X+ or Y+)	Fraction (ideal)	Fraction (actual)	% Error	Notes
1	16	0.0625	0.0625	0.00 %	Sum of X- and X+ fractions
2	15	0.1250	0.1250	0.00 %	or Y- and Y+ fractions
3	14	0.1875	0.1861	-0.75 %	= 1.0625
4	13	0.2500	0.2483	-0.68 %	Independent of signal position
5	12	0.3125	0.3158	1.06 %	
6	11	0.3750	0.3731	-0.51 %	
7	10	0.4375	0.4412	0.85 %	
8	9	0.5000	0.5000	0.00 %	
9	8	0.5625	0.5618	-0.12 %	
10	7	0.6250	0.6250	0.00 %	
11	6	0.6875	0.6818	-0.83 %	
12	5	0.7500	0.7500	0.00 %	
13	4	0.8125	0.8021	-1.28 %	
14	3	0.8750	0.8876	1.44 %	
15	2	0.9375	0.9375	0.00 %	
16	1	1.0000	1.0000	0.00 %	

Note: Errors exclude 1% component tolerances

# **Output Signals**

X- = (SiPM signal) \* (encoder gain) \* (X- fraction)

X+ = (SiPM signal) \* (encoder gain) \* (X+ fraction)

Y- = (SiPM signal) \* (encoder gain) \* (Y- fraction)

Y+ = (SiPM signal) \* (encoder gain) \* (Y+ fraction)

Typical event position calculation:

X column = (X + - X -) / (X + + X -)

Y row = (Y+ - Y-) / (Y+ + Y-)

# **Example**

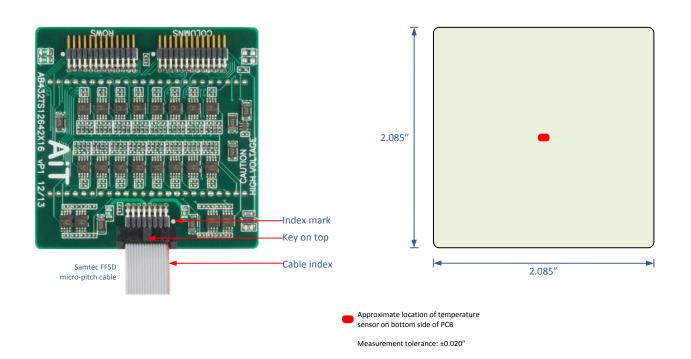
SiPM signal at column=4, row=3 (excluding encoder gain)					
<b>X-</b> = (Col4 signal) * 0.2483	<b>X+</b> = (Col4 signal) * 0.8021	<b>Y-</b> = (Row3 signal) * 0.1861	<b>Y+</b> = (Row3 signal) * 0.8876		

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# **Mechanical**

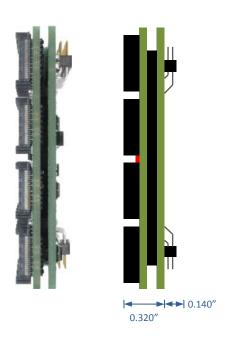
# **Top View**



# Side View, Base Attached to Array

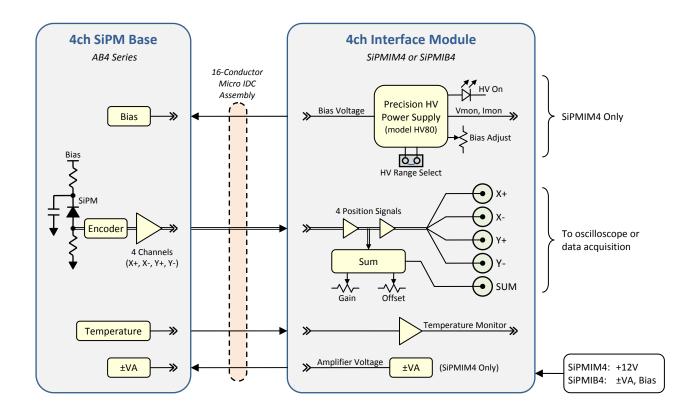
# Array Base 0.140"

# Side View, Base Only





# **AB4 Series 4-Channel SiPM Evaluation System**



### Summary

A 4-channel SiPM array evaluation system consists of an AB4 series 4-channel SiPM Base plus a SiPMIM4 ("IM4") Interface Module or SiPMIB4 ("IB4") Interface Board. The AB4 connects to the IM4 or IB4 through a micro-pitch ribbon cable that permits versatile placement of the Base.

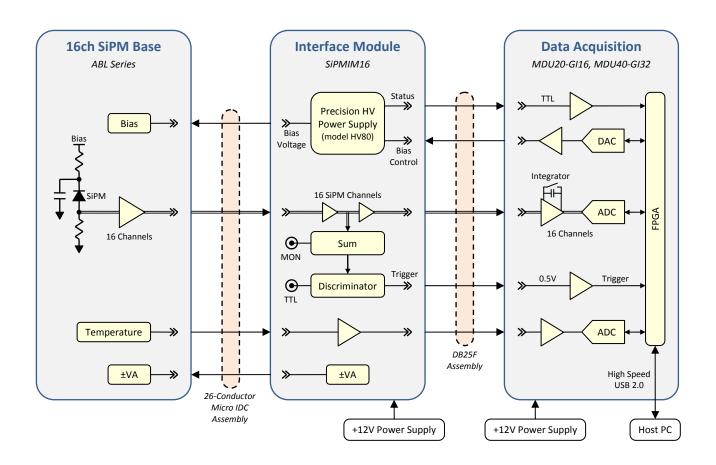
The IM4 and IB4 buffers four SiPM position signals and forms an analog sum of all SiPM position signals. Position signals and sum are provided on five BNC receptacles or optional LEMO EP.00 coaxial receptacles for use with an oscilloscope or external data acquisition. The sum may be used to form a trigger.

### **SiPMIM4 and SiPMIB4 Differences**

The IM4 is provided in an aluminum enclosure and requires only an external 12V power supply to operate. It internally generates amplifier voltages and bias voltage required by the Base. The IB4 is a low-cost unenclosed circuit board. It requires external amplifier voltages and bias voltage to be provided through screw terminals.



# 16-Channel SiPM Readout System



# **Summary**

A 16-channel SiPM array readout system consists of an ABL series 16-channel SiPM Base, a SiPMIM16 ("IM16") Interface Module, and a 16/32-channel simultaneous sampling USB gated integrator model MDU20-GI16 or MDU40-GI32.

### **SiPM Base and Interface Module**

The ABL Base connects to the IM16 through a micro-pitch ribbon cable that permits versatile placement of the Base. The IM16 powers the Base, buffers SiPM signals, and forms a trigger from the discriminated analog sum of all SiPM signals.

### MDU20-GI16 and MDU40-GI32

The MDU20-GI16 has 16 simultaneous gated integrators followed by 16 simultaneous sampling ADCs. Each integrator is preceded by a 100ns analog delay to compensate for trigger latency. A 16-bit DAC controls SiPM bias and a 16-bit ADC monitors SiPM temperature. The IM16 connects to the MDU20-GI16 through a DB25F cable assembly. The MDU40-GI32 is a dual version of the MDU20-GI16 capable of controlling two IM16s.

Tileable 4+32 Channel Base for a 4x4 Array of the Hamamatsu S12642-0404PB

# **Safety Information**



# WARNING – High Voltage

- High voltage may be present during operation
- High voltage stored on capacitors may be present after power is removed
- Improper handling may result in personnel injury or equipment damage

This high-voltage device must be used only by personnel trained and qualified in safe handling, installation, and operation of high-voltage equipment.



# **CAUTION – Electrostatic Discharge (ESD) Sensitivity**

The circuit board can be damaged by electrostatic discharge. Observe precautions for handling electrostatic sensitive devices. Handle only at static-safe workstations.

# **High-Gain Photodetectors**

High-gain photodetectors such as silicon photomultipliers may conduct damaging currents if exposed to high optical signal levels while the bias voltage is applied, or if the bias voltage exceeds the recommended operating range. These devices must be operated only in low-light conditions, and only within the manufacturer's recommended bias voltage range.

# **Handling and Disassembly**

This product may be provided with or without a protective enclosure. Disassembled enclosure components and circuit boards may contain sharp edges. Take appropriate safety precautions while assembling or disassembling the enclosure and handling disassembled components.

# **Indoor Use Only**

Do not operate this product in a wet/damp environment. Do not operate in an explosive atmosphere.

Use of this product, and AiT Instruments' liability related to use of this product, is further governed by AiT Instruments' standard terms and conditions of sale, which were provided upon purchase of this product.